

Switch mode **Dual Schottky Barrier Power Rectifiers**

Using the Schottky Barrier principle with a Refractory metal capable of high temperature operation metal. The appropriate barrier technology allows for reliable operation up to 150°C junction temperature. Typical applications are in switching Mode Power Supplies such as adaptors, DC/DC converters, freewheeling and polarity protection diodes.

Features

- * Low Forward Voltage.
- * Low Switching noise.
- * High Current Capacity
- * Guarantee Reverse Avalanche.
- * Guard-Ring for Stress Protection.
- * Low Power Loss & High efficiency.
- * High Operating Junction Temperature
- * Low Stored Charge Majority Carrier Conduction.
- * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O
- * Pb free
- * In compliance with EU RoHs directives



MAXIMUM RATINGS

Characteristic	Symbol	S20T100FN	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	100	V
RMS Reverse Voltage	V _{R(RMS)}	70	V
Average Rectifier Forward Current (per diode) Total Device (Rated V_R),	I _{F(AV)}	10 20	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	20	A
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions half-ware, single phase, 60Hz)	I _{FSM}	150	A
Operating and Storage Junction Temperature Range	T _J , T _{stg}	-65 to +150	°C

THERMAL RESISTANCES

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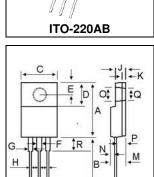
ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Min.	Тур.	Max.	Unit
Maximum Instantaneous Forward Voltage ($I_F = 10 \text{ Amp } T_C = 25^{\circ}C$) ($I_F = 10 \text{ Amp } T_C = 125^{\circ}C$)	V _F		0.7 6 0.66	0.80	· v
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_C = 25^{\circ}C$) (Rated DC Voltage, $T_C = 125^{\circ}C$)	FUE TER	E F	0.02 9.8	0.05	mA
RA-D-1110 Ver.C	S.W.				

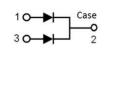


S20T100FN

SCHOTTKY BARRIER



DIM	MILLIMETERS			
DIN	MIN	MAX		
Α	14.80	16.10		
В	12.65	14.40		
С	9.70	10.36		
D	4.60	6.80		
E	2.50	3.50		
F	0.90	1.45		
G	0.90	1.45		
Н	0.50	0.90		
1	2.40	2.70		
J	2.34	3.30		
K	0.55	1.30		
L	0.36	0.80		
М	4.20	4.90		
Ν	1.10	1.80		
0	2.90	3.50		
Р	2.30	3.15		
Q	2.90	3.50		
R	2.80	4.85		





S20T100FN

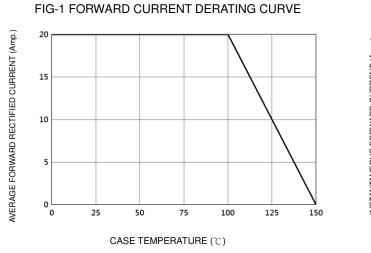
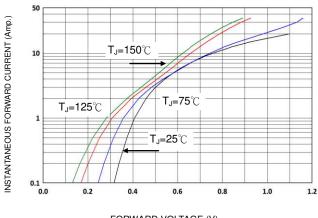
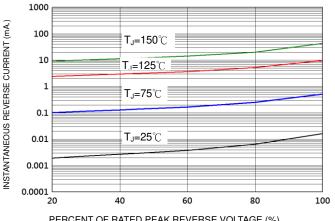


FIG-2 TYPICAL FORWARD CHARACTERISTICS



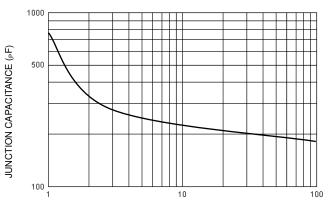
FORWARD VOLTAGE (V)

FIG-3 TYPICAL REVERSE CHARACTERISTICS

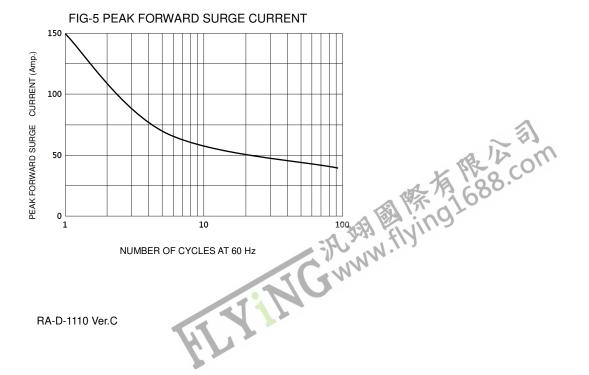


PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

FIG-4 TYPICAL JUNCTION CAPACITANCE



REVERSE VOLTAGE (V)





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